



DMN5L06DWK

DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Dual N-Channel MOSFET
- Low On-Resistance (1.0V max)
- Very Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- ESD Protected up to 2kV
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)
- Qualified to AEC-Q101 standards for High Reliability

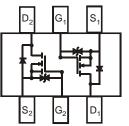
Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.006 grams (approximate)





Top View



Top View Internal Schematic

Ordering Information (Note 3)

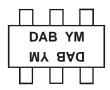
Part Number	Case	Packaging
DMN5L06DWK-7	SOT363	3000/Tape & Reel

Notes: 1. No purposefully added lead.

2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com.

3. For packaging details, go to our website at http://www.diodes.com.

Marking Information



DAB = Marking Code YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

Year	200	6	2007		2008	20	09	2010		2011	2	2012
Code	Т		U		V	V	V	Х		Y		Z
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



Maximum Ratings @T_A = 25°C unless otherwise specified

Chara	cteristic	Symbol	Value	Unit
Drain Source Voltage		V _{DSS}	50	V
Gate-Source Voltage		V _{GSS}	±20	V
Drain Current (Note 4)	Continuous Pulsed (Note 5)	I _D	305 800	mA

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 4)	PD	250	mW
Thermal Resistance, Junction to Ambient	$R_{ ext{ heta}JA}$	500	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

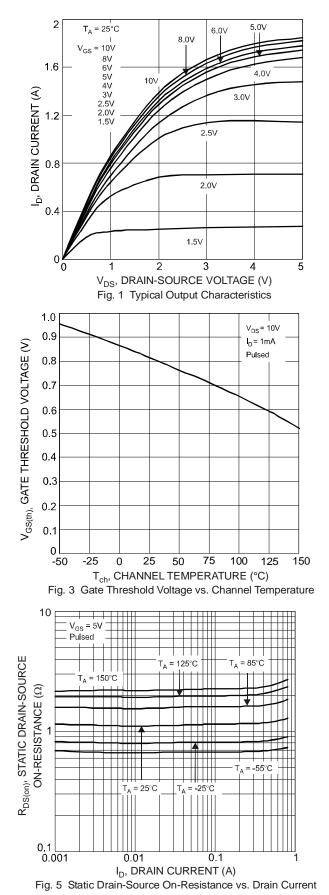
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)		• • • • • • •		• 76		•	
Drain-Source Breakdown Voltage		BV _{DSS}	50	—	—	V	$V_{GS} = 0V, I_D = 10\mu A$
Zero Gate Voltage Drain Current	@ T _C = 25°C	IDSS	_		60	nA	$V_{DS} = 50V, V_{GS} = 0V$
Gate-Body Leakage		I _{GSS}	_	_	1 500 50	μA nA nA	$V_{GS} = \pm 12V, V_{DS} = 0V$ $V_{GS} = \pm 10V, V_{DS} = 0V$ $V_{GS} = \pm 5V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 6)				-		-	
Gate Threshold Voltage		V _{GS(th)}	0.49		1.0	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
Static Drain-Source On-Resistance		R _{DS (ON)}			3.0 2.5 2.0	Ω	
On-State Drain Current		I _{D(ON)}	0.5	1.4		А	$V_{GS} = 10V, V_{DS} = 7.5V$
Forward Transconductance		Y _{fs}	200	_		mS	V _{DS} =10V, I _D = 0.2A
Source-Drain Diode Forward Voltage		V _{SD}	0.5		1.4	V	$V_{GS} = 0V, I_{S} = 115mA$
DYNAMIC CHARACTERISTICS							
Input Capacitance		Ciss	_	_	50	pF	
Output Capacitance		Coss			25	pF	V _{DS} = 25V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance					5.0	pF	

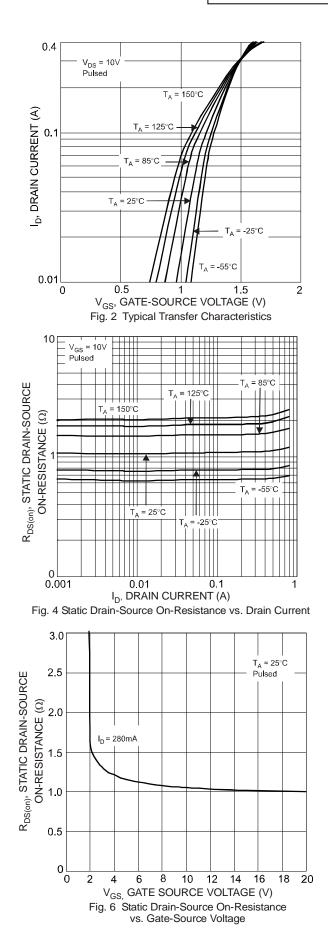
Notes: 4. Device mounted on FR-4 PCB.

5. Pulse width ≤10µS, Duty Cycle ≤1%.
6. Short duration pulse test used to minimize self-heating effect.

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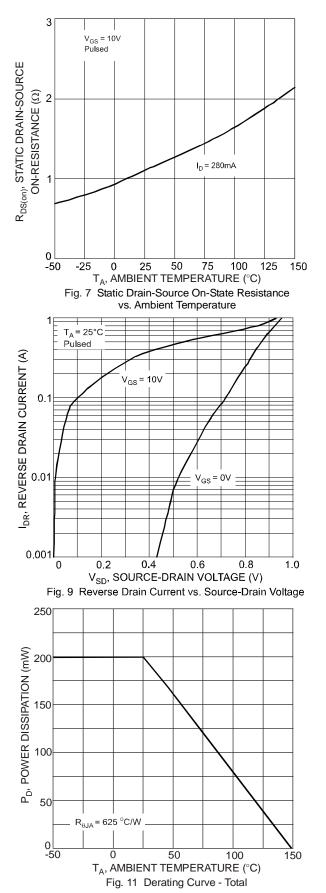


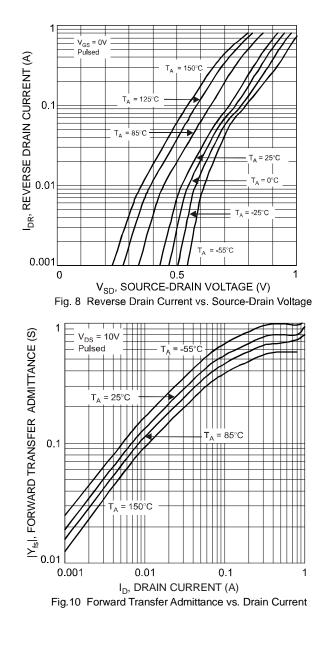




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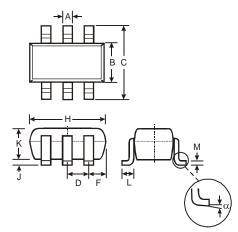






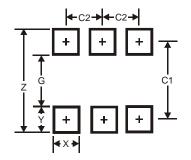


Package Outline Dimensions



	SOT363					
Dim	Min Max					
Α	0.10	0.30				
в	1.15	1.35				
C	2.00	2.20				
D	0.65 Typ					
F	0.40 0.45					
Н	1.80	2.20				
J	0 0.10					
κ	0.90 1.00					
L	0.25 0.40					
М	0.10 0.22					
α	0°	8°				
All Dimensions in mm						

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.5
G	1.3
Х	0.42
Y	0.6
C1	1.9
C2	0.65



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